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STMicroelectronics 2STF2280

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2STF2280

Low voltage high performance PNP power transistor

Preliminary data

Features

- Low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed

Applications

- DC-DC converter, voltage regulation
- General purpose switching equipment

Description

The device is a PNP transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

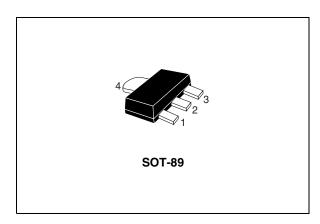


Figure 1. Internal schematic diagram

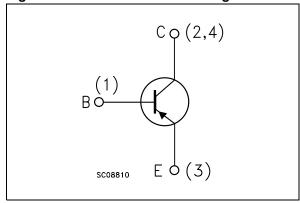


Table 1. Device summary

Order code	Marking	Package	Packaging
2STF2280	2280	SOT-89	Tape and reel

January 2010 Doc ID 16984 Rev 1 1/7



Electrical ratings 2STF2280

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-80	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-80	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
I _C	Collector current	2	Α
I _{CM}	Collector peak current (t _P < 5 ms)	4	Α
I _B	Base current	0.5	Α
I _{BM}	Base peak current (t _P < 5 ms)	1	Α
P _{TOT}	Total dissipation at T _{amb} = 25°C	1.4	W
TJ	Operating junction temperature -65 to 150		°C
T _{STG}	Storage temperature	-03 to 150	

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient max	89	°C/W

^{1.} Device mounted on a PCB area of 1 cm².





2STF2280

Electrical characteristics

2 Electrical characteristics

 T_{CASE} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = -80 V			-500	μА
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} = -80 V			-1	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = -5 V			-100	μΑ
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = -10 mA	-80			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$ $I_C = -1 \text{ A}, I_B = -100 \text{ mA}$	-15		-100 -250	mV mV
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$ $I_C = -1 \text{ A}, I_B = -100 \text{ mA}$			-1 -1.1	V V
h _{FE} ⁽¹⁾	DC current gain	$I_C = -100 \text{ mA}, V_{CE} = -2 \text{ V}$ $I_C = -500 \text{ mA}, V_{CE} = -2 \text{ V}$ $I_C = -1 \text{ A}, V_{CE} = -2 \text{ V}$	140 100 80	190	300	
f _T	Transition frequency	I _C = -0.1 A, V _{CE} = -10 V		50		MHz

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %.





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Datasheet of 2STF2280 - TRANS PNP 80V 2A SOT-89

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Package mechanical data

2STF2280

3 Package mechanical data

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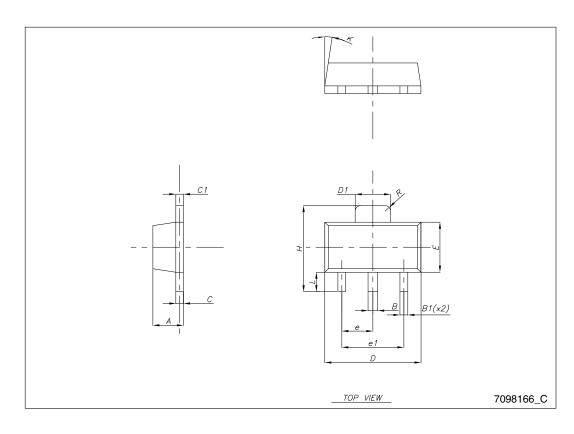


2STF2280

Package mechanical data

SOT-89 mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
A	1.40		1.60	
В	0.44		0.56	
B1	0.36		0.48	
С	0.35		0.44	
C1	0.35		0.44	
D	4.40		4.60	
D1	1.62		1.83	
E	2.29		2.60	
е	1.42		1.57	
e1	2.92		3.07	
Н	3.94		4.25	
К	1°		8°	
L	0.89		1.20	
R		0.25		







Revision history 2STF2280

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
14-Jan-2010	1	Initial release.





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Datasheet of 2STF2280 - TRANS PNP 80V 2A SOT-89

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2STF2280

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